# Lead-free Processing Compatible with Halogen-free Required EM-285/ EM-285B

## **Outline**

- 1. Compression of Basic Material Property
- 2. Related PCB Processing Evaluation
- 3. Reliability Test
- 4. Conclusion



## **General property**

Thickness: 1.0mm

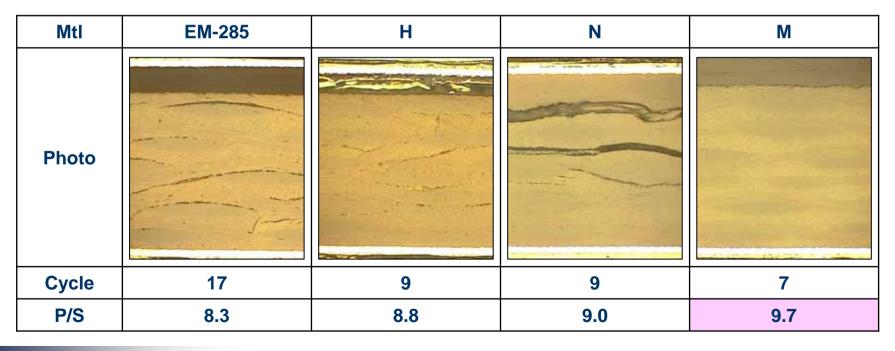
Item	Condition	Unit	EM-285	Н	N	M
Tg	TMA		152	152	154	156
T288(unclad)	TMA	Min	> 60	> 60	> 60	> 60
T288(clad)	TMA	Min	8	<1	3.5	3.5
Td (5% loss)	TGA		364	338	349	334
1	TMA(50~120 )	ppm/	49	56	44	30
2	TMA(180~260 )	ppm/	201	220	235	202
CTE	TMA(50~260 )	%	2.3	2.9	2.9	2.2
Dk	1 MHz	-	4.8	4.8	4.8	4.9
DK	1 GHz	-	4.7	4.7	4.6	4.8
Df	1 MHz	10E-3	0.007	0.007	0.010	0.010
וט	1 GHz	10E-3	0.009	0.009	0.016	0.012



## Peel strength vs. thermal stress

Thickness: 1.0mm 1/1

Item	Condition	Unit	EM-285	Н	N	M
Peel	As received	lb/in	8.1~8.4	8.7~8.9	8.9~9.0	9.7~9.8
strength (1oz)	After thermal stress	lb/in	8.0~8.3	8.4~8.8	8.8~9.1	9.4~9.5
Thermal stress	Solder dip 288 x 10s	cycle	17~20	7~9	9~11	6-8

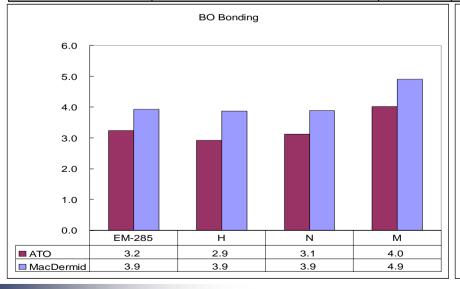


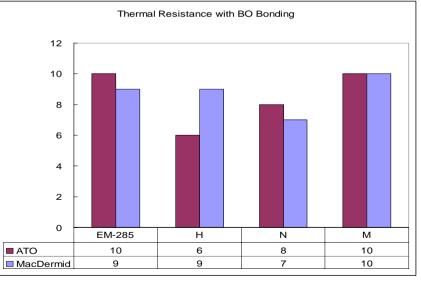


## **BO** bonding vs. thermal stress

Construction:  $1oz + 7628 \times 5 + 1oz$ 

Chemical	Condition	Unit	EM-285	Н	N	M
АТО	As received		3.0~3.4	2.8~3.1	3.0~3.4	3.8~4.3
AIO	After thermal stress	lb/in	3.9~4.0	3.6~4.1	3.7~4.0	4.8~5.0
MaaDawaid	As received	ID/III	3.1~3.4	2.8~3.1	2.8~3.1	3.7~3.9
MacDermid	After thermal stress		3.6~4.1	3.5~3.8	3.7~4.0	4.6~5.0
Thermal	ATO Bond Film	ovele	8~10	5~6	5~8	9~11
stress cycle	MacDermid	cycle	8~9	8~10	7~9	10~11





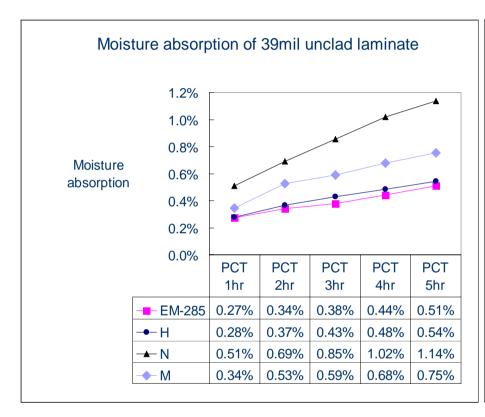


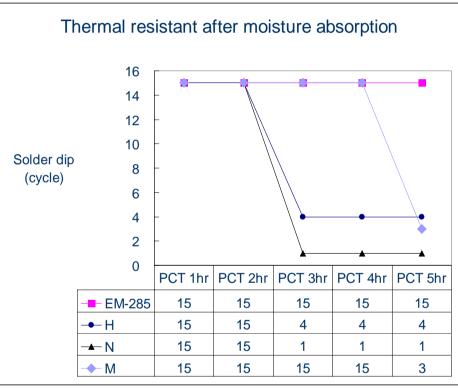
## **BO** bonding vs. thermal stress

MtI	EM-285	Н	N	М
АТО				
Cycle	10	6	8	10
P/S	3.2	2.9	3.1	4.0
Mtl	EM-285	Н	N	М
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Mac Dermid				
	9	9	7	10



### Moisture absorbed & thermal resistance







# **PCB Processing Evaluation**

## **Drilling Processing**

#### Method

**Layer Count: 4 Layers** 

Thickness: 1.6mm

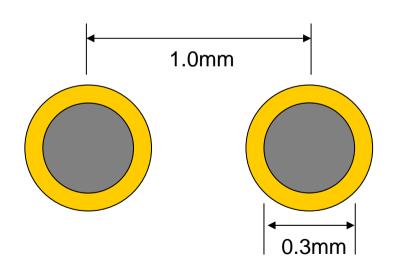
**Drilling Hole Size: 0.3mm** 

Wall to wall: 0.7mm

7628

0.039",1/1

7628





## **PCB Processing Evaluation**

## **Drilling Processing**

Material	Speed (krpm)	Chip load (mil/rev)	Hit
Regular FR-4	150	0.7	2500
N Company	150	0.7	2500
H Company	150	0.7	2500
EM-285	150	0.7	2500

- 1. Machine: Tong-Tai 160krpm
- 2. Taiwan Union 0.3 mm UC drilling bit
- 3. 0.2 mm thickness of entry, 1.5 mm thickness of urethane clad
- 4. Stack-up: 2 PNLs of stack height (Total 3.2 mm)

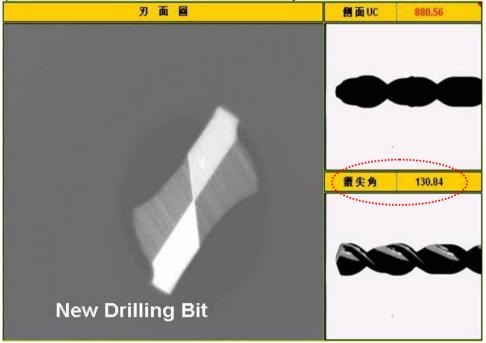


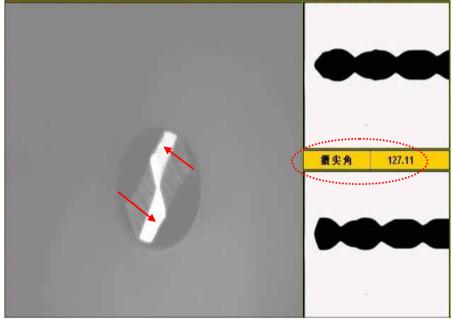
Reducing Drilling Bit Abrasion Study



Thickness 1.6mm,
Diameter 0.3mm,
Speed 150krpm,
Chip load 0.7 mil/rev, 2500 Hit

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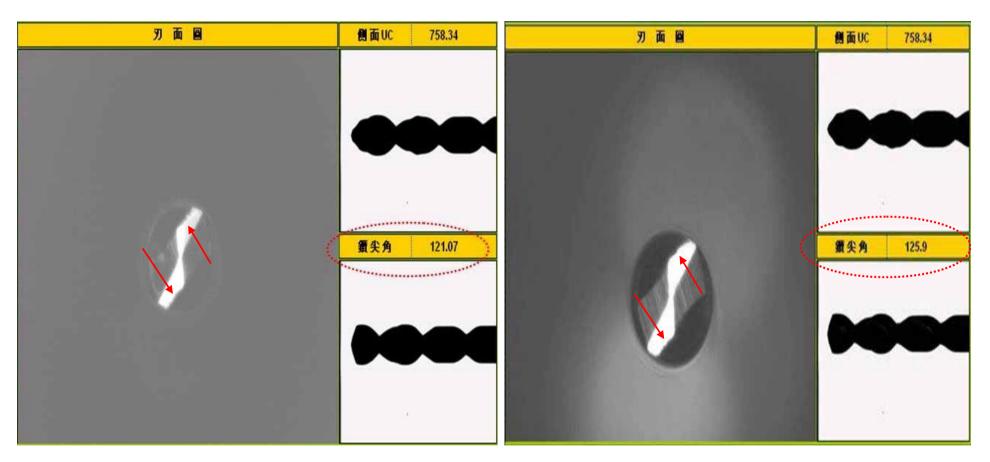
755.56

Point Angle of New Drilling Bit: 130 degree

Regular FR-4 Material: 127 degree



## Reducing Drilling Bit Abrasion Study

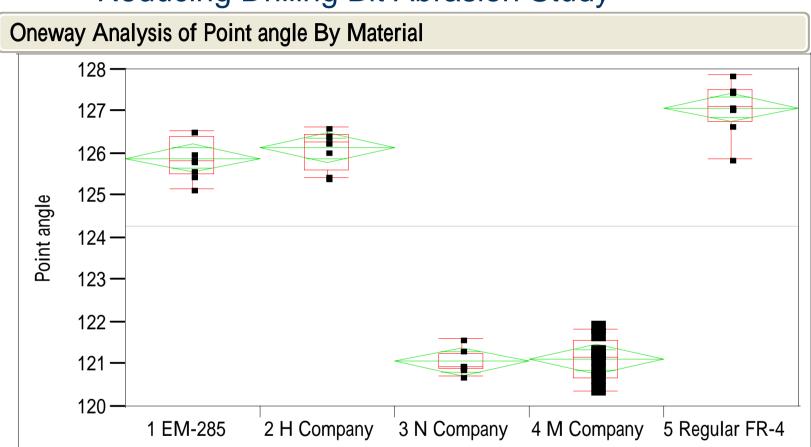


N Company: 121 degree

EM-285 : 126 degree



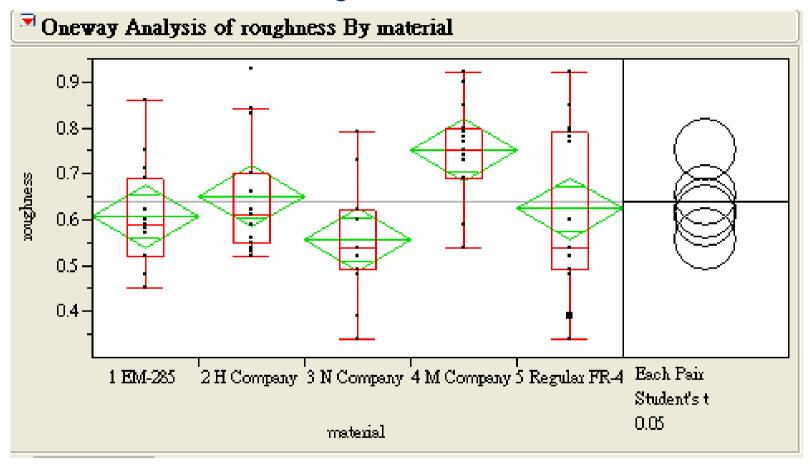
## Reducing Drilling Bit Abrasion Study



Drilling bit abrasion ratio of EM-285 is improved 80% above than N company material



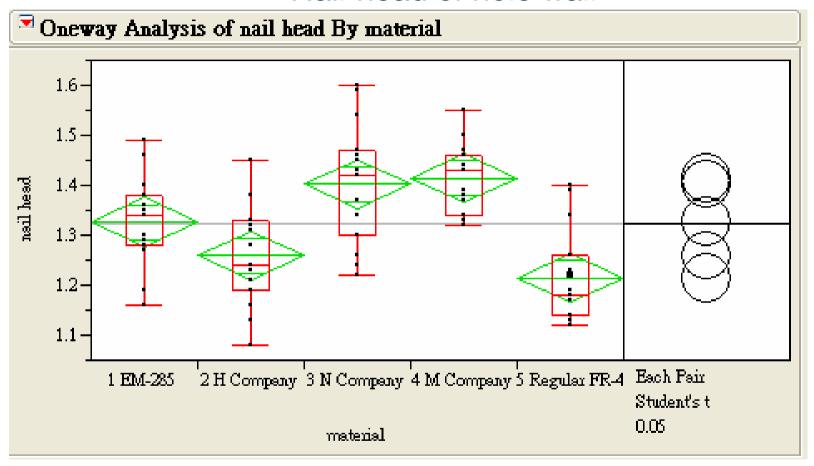
## Roughness of hole wall



Performance of hole wall roughness between regular FR-4 material and EM-285 is similar



#### Nail-head of hole wall



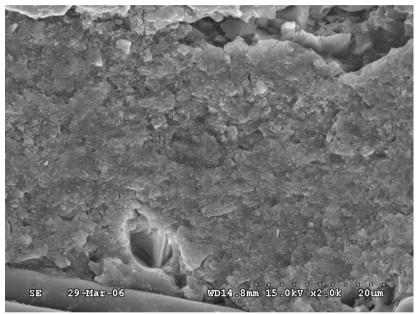
Performance of nail-head between regular FR-4 material and EM-285 is similar



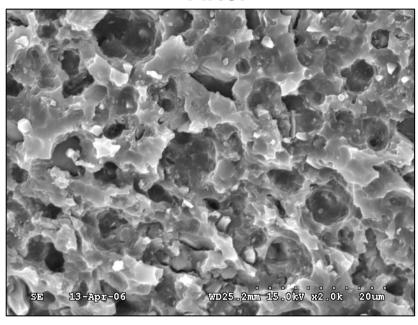
## **PCB Processing Evaluation**

## Desmear weight loss





**After** 



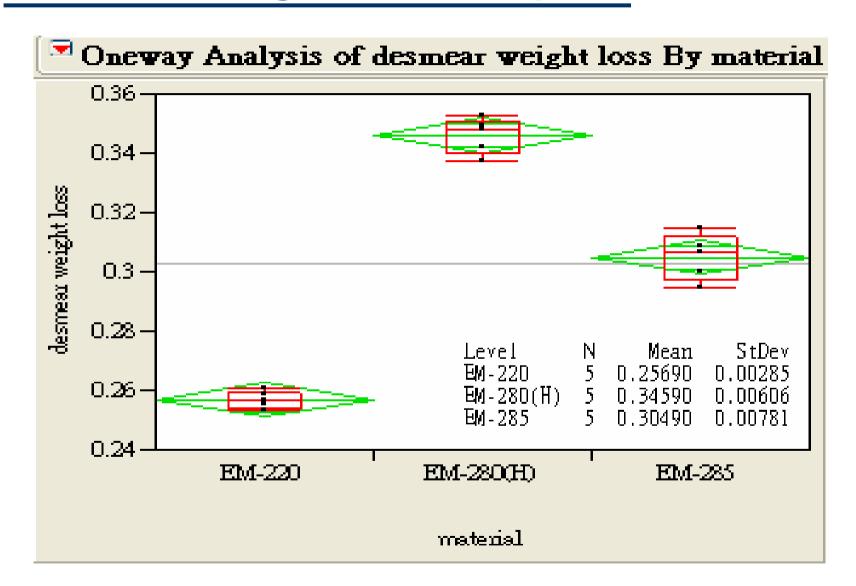
Weight loss control at 0.20 ~ 0.40 mg / cm<sup>2</sup>

**Sweller temperature: 60** / time 5 minutes

Desmear temperature: 80 / time 9 minutes



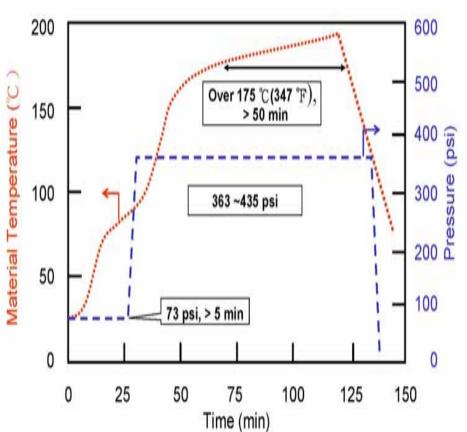
# Desmear weight loss comparison





# **PCB Processing Parameter Suggestion**

## Press cycle



Kiss pressure: 3.5~7 kgf / cm<sup>2</sup>

Heat rate: 1.8 ~ 3.0 / min

Full pressure: 25 ~ 30 kgf / cm<sup>2</sup>

Apply Full pressure at: 85 ~ 100

Curing condition: >175 / 50 min

(Minimum peak temperature in curing condition: 195)

\*The heating rate higher will be better for peeling strength and inner layer pattern filling, while the lower will be better for press flow. Please contact us for setting suitable press cycle if necessary.



# **PCB Processing Parameter Suggestion**

Pro	cess		Condition			
Surface Clean		Std. Practice				
A.	O.I.	5	Std. Practice			
Oxide t	reatment	Std.	Black or Brow	wn		
Oxide	e Bake	1	20 40 min			
Hole diameter ( mm )		0.3	0.4	0.5		
Spindle Speed ( Krpm )		150	120	100		
In Feed ( inch / min )		120	102	90		
Chip Load	l ( mil / rev )	0.8	0.85	0.9		
Number of Hits		1500	1500	1500		
Sweller ( Uyemura )	Vertical	60 for 5 min.				
KMnO <sub>4</sub> ( Uyemura )	Vertical	80 for 9 min.				



# **Additional Suggestion during Processing**

For improving material moisture absorbed in processing, post-baked treated would be suggested as several processing:

- 1. Finished board before packing
  - 1-1 HASL: 150 degree C for 4 hours
  - 1-2 ENIG finished: 120 degree C for 4 hours
  - 1-3 Before OSP: 150 degree C for 4 hours
- Solder mask re-work or WIP over 2 weeks150 degree C for 4 hours



#### **Test Pattern & Construction**

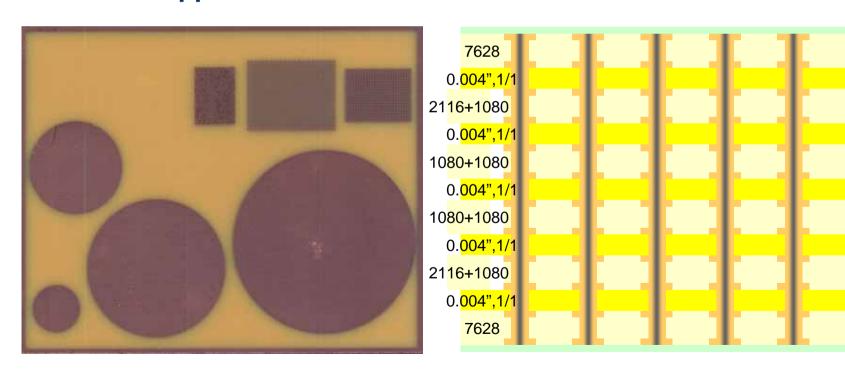
Thickness: 2.0mm

**Layer Count: 12** 

Hole Diameter: 0.3mm

Wall to wall: 0.3 / 0.45 / 0.7mm

**Ground Copper Diameter: 0.5/ 1.0/ 1.5/ 2.0 inch** 





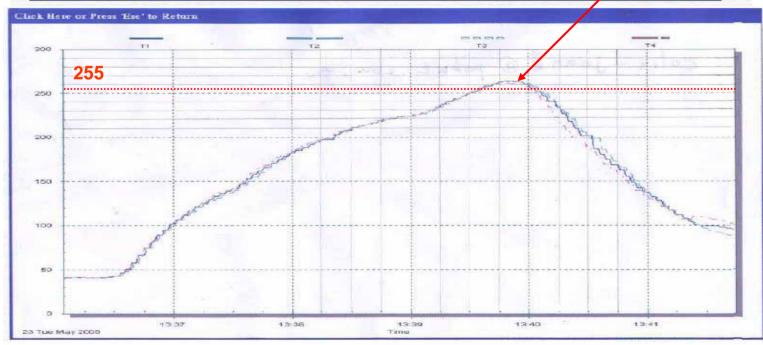
## **IR Reflow Condition**

#### IR Reflow溫度設定値(單位:℃)

設定値	第1段	第2段	第3段	第4段	第5段
上爐溫	250	230	260	250	320
下爐溫	250	230	260	250	320

#### IR Reflow溫度實測值

項目	IPC/JEDEC J-STD-020C	實測值
預熱段時間(150~200℃)	60~180sec	63
平均昇溫速率(200~260℃)	<3℃/sec	0.65
>217℃時間	60~150sec	112
高溫段時間(255~260℃)	20~40sec	. 29
最高溫度	260℃	262
降溫速率(260~140℃)	<6°C/sec	/3.43
昇溫時間(25~260℃)	<8分	4.5





## Copper Ground with IR Reflow

N = 12

Item	Condition	Pattern	unit	EM-285	Н	N	M
		0.5"		>10	7~8	8~9	>10
	As	1.0"		>10	6~8	7~9	>10
	received	1.5"		>10	5~7	7~8	>10
Copper		2.0"	ovolo	>10	4~7	6~8	>10
ground	85 , 85% RH, 40hr treated	0.5"	cycle	>10	6~7	5~8	>10
		1.0"		>10	5~8	6~7	>10
		1.5"		>10	6~7	5~6	>10
		2.0"		> 10	5~7	4~6	>10

Thermal resistance with ground copper area improved in EM-285



#### **Hole Wall Crack after IR Reflow**

N = 45

Material	Wall to wall	Delam	ination Ra	tio (%)
Material	(mm)	3 cycles	6 cycles	9 cycles
	0.30	13	41	87
EM-285	0.45	0	35	77
	0.70	0	0	13
	0.30	21	51	93
н	0.45	0	48	86
	0.70	0	9	21
	0.30	56	83	100
N	0.45	33	78	93
	0.70	7	26	37
	0.30	47	73	100
M	0.45	22	60	91
	0.70	4	18	27

EM-285 Can Pass the wall to wall 0.45mm by 3 Cycles and 0.70mm by 6 Cycles of Lead-Free IR Reflow



## Micro-sectioning of hole wall with IR reflow 6 cycles

Wall to wall (mm)	EM-285	н	N	M
0.7				
0.45				



## Conclusion

## EM-285 Advantage

- Better Thermal Resistance (Lead-Free Requirement)
- 2. Better Capability to Reduce the Drilling Bit Abrasion

3. Better Electrical Performance in High Frequency Application (Low Df)

